



DATA SHEET

SEMICONDUCTOR

SB120~SB1200

1 AMPERE SCHOTTKY BARRIER RECTIFIERS VOLTAGE 20 to 200 Volts CURRENT - 1.0 Ampere

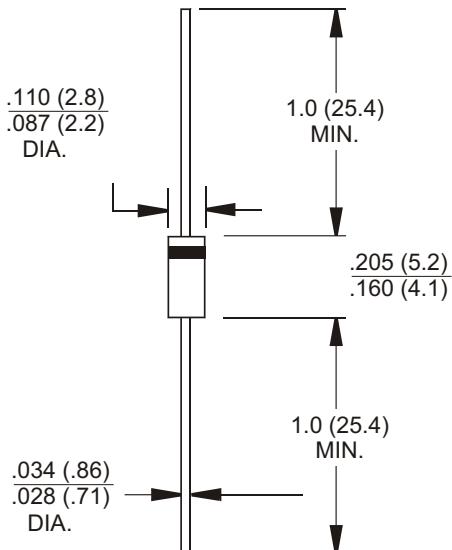


DO-41

Unit:inch(mm)

FEATURES

Plastic package has Underwriters Laboratory
Flammability Classification 94V-O utilizing
Flame Retardant Epoxy Molding Compound.
1 ampere operation at TA=75°C with no
thermal runaway.
Exceeds environmental standards of MIL-S-19500/228
For use in low voltage,high frequency inverters ,free wheeling ,
and polarity protection applications .
High temperature soldering : 260°C / 10 seconds at terminals
Pb free product available : 99% Sn above meet RoHS
environment substance directive request



MECHANICAL DATA

Case: DO-41 Molded plastic
Terminals: Axial leads, solderable per MIL-STD-202, Method 208
Polarity: Color band denotes cathode
Mounting Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

	SB120	SB130	SB140	SB150	SB160	SB180	SB1100	SB1200	UNIT				
Peak Reverse Voltage,Repetitive ; VRM	20	30	40	50	60	80	100	200	V				
Maximum RMS Voltage	14	21	28	35	42	56	70	140	V				
DC Reverse Voltage; VR	20	30	40	50	60	80	100	200	V				
Maximum Forward Voltage at 1.0A	0.50		0.70		0.85		0.95		V				
Maximum Average Forward Rectified Current .375" Lead Length at TA=75°C	1.0							A					
Peak Forward Surge Current, IFM (surge):8. 3ms single half sine-wave superimposed on rated load(JEDEC method)	30.0							A					
Maximum Full Load Reverse Current,Full Cycle Average at TA=75°C	30.0							mA					
Maximum DC Reverse Current at TA=25°C	0.5							mA					
At Rated DC Blocking Voltage TA=100°C	10.0							mA					
Typical Junction capacitance (Note 1)	110							pF					
Typical Thermal Resistance R_{θJA} (Note 2)	80							/W					
Operating Temperature Range TJ	-55 to +125			-55 to +150									

NOTES:

1. Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
2. Thermal Resistance from Junction to Ambient .

DEVICE CHARACTERISTICS

SB120~SB1200

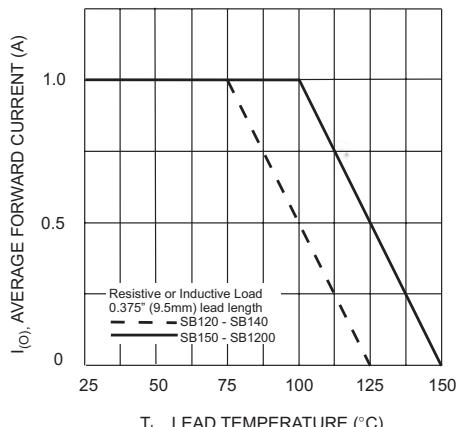


Fig. 1 Forward Current Derating Curve

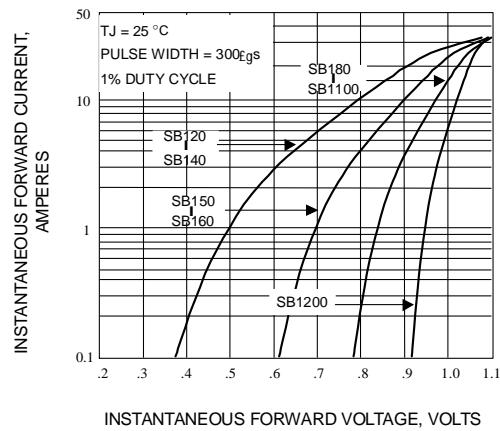


Fig. 2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

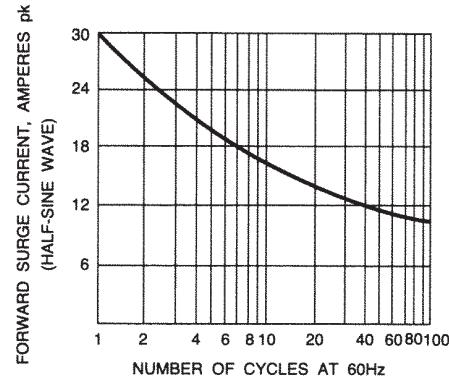


Fig. 3 – MAXIMUM NON-REPETITIVE SURGE CURRENT

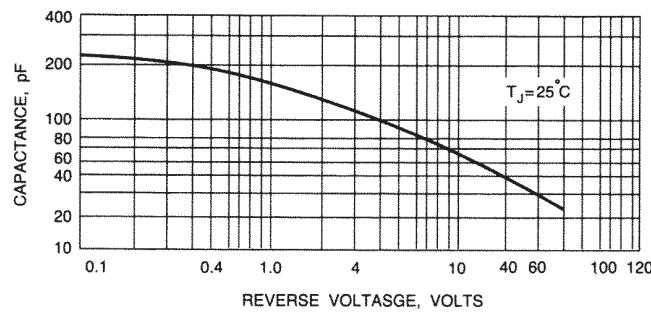


Fig. 4 – TYPICAL JUNCTION CAPACITANCE